



DMN2024UFDF

20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
	$22m\Omega @ V_{GS} = 4.5V$	7.1A
2017	$26m\Omega @ V_{GS} = 2.5V$	6.5A
20V	36mΩ @ Vgs = 1.8V	5.5A
	50mΩ @ V _{GS} = 1.5V	4.7A

Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

Applications

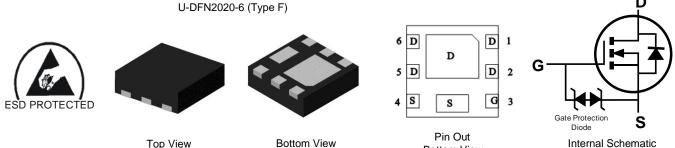
- **Battery Management Application**
- **Power Management Functions**
- **DC-DC** Converters

Features

- 0.6mm Profile—Ideal for Low Profile Applications
- PCB Footprint of 4mm² •
- Low Gate Threshold Voltage
- Fast Switching Speed
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: U-DFN2020-6 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.0065 grams (Approximate)



Bottom View

Internal Schematic

Ordering Information (Note 4)

Part Number	Reel Size (inches)	Quantity Per Reel
DMN2024UFDF-7	7	3,000
DMN2024UFDF-13	13	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and l ead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site1



OA = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н		J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



OA = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Kev

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	8	9	0	1	2	3	4	5	6	7	8	9
Week	1-26			27-52				53				
Code	A-Z			a-z				Z				

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	Х	Y	Z



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		Vdss	20	V	
Gate-Source Voltage	V _{GSS}	±10	V		
Continuous Drain Current (Note 6) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	lo	7.1 5.6	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	•	ldм	40	A
Continuous Source-Drain Diode Current		ls	2.6	A	
Avalanche Current (Note 7) L = 0.1mH	las	12	A		
Avalanche Energy (Note 7) L = 0.1mH			Eas	8	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.96	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Roja	130	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.67	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	75	80 M
Thermal Resistance, Junction to Case (Note 6)	Rejc	16	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	20		—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	—		1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—		±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	0.5		1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			15	22		$V_{GS} = 4.5V, I_D = 4A$	
Static Drain-Source On-Resistance	Rds(on)		17	26	mΩ	VGS = 2.5V, ID = 4A	
	NDS(ON)		20	36	11132	VGS = 1.8V, ID = 4A	
			23	50		Vgs = 1.5V, ID = 4A	
Diode Forward Voltage	Vsd	—	0.7	1.0	V	$V_{GS} = 0V$, $I_{S} = 5A$	
DYNAMIC CHARACTERISTICS (Note 9)						-	
Input Capacitance	Ciss	—	647	—			
Output Capacitance	Coss	—	78	—	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	38	—		1 = 1.00012	
Gate Resistance	Rg	—	400	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	6.5	—			
Total Gate Charge (VGS = 10V)	Qg	_	14.8	_			
Gate-Source Charge	Qgs	—	1.1	—	nC	V _{DS} = 10V, I _D = 6.5A	
Gate-Drain Charge	Qgd	—	1.7	—			
Turn-On Delay Time	tD(ON)	—	98	—			
Turn-On Rise Time	tR	—	140	—		$V_{DS} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t _{D(OFF)}	—	1024	—	ns	$R_G = 6\Omega$, $R_L = 10\Omega$, $I_D = 1A$	
Turn-Off Fall Time	tF	—	434	—	1		
Reverse Recovery Time	trr	_	245	_	ns	IF = 1A, di/dt = 100A/µs	
Reverse Recovery Charge	Q _{RR}		149		nC	IF = 1A, di/dt = 100A/µs	

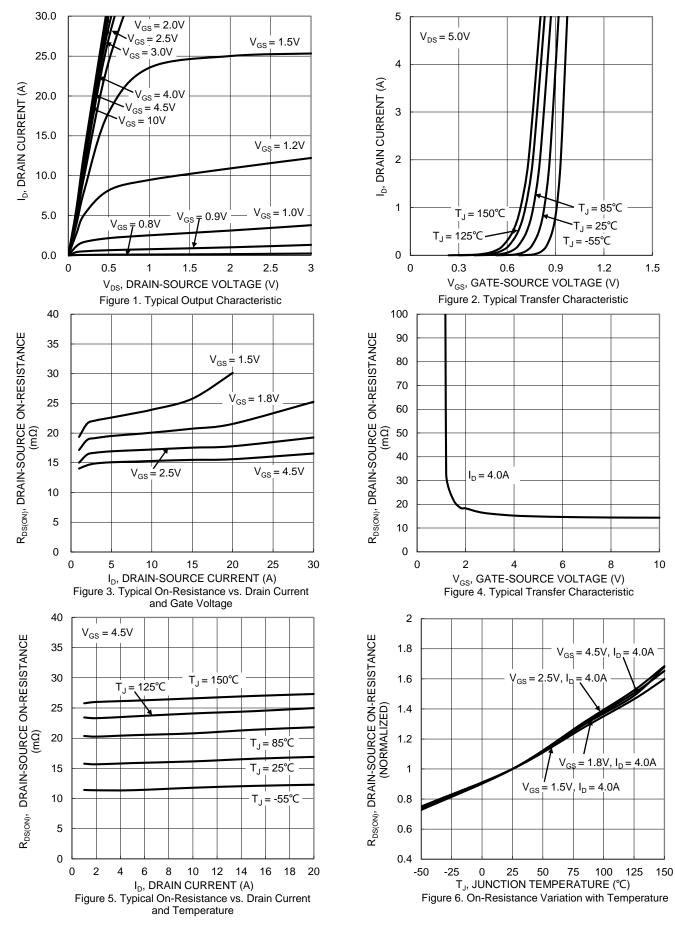
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.



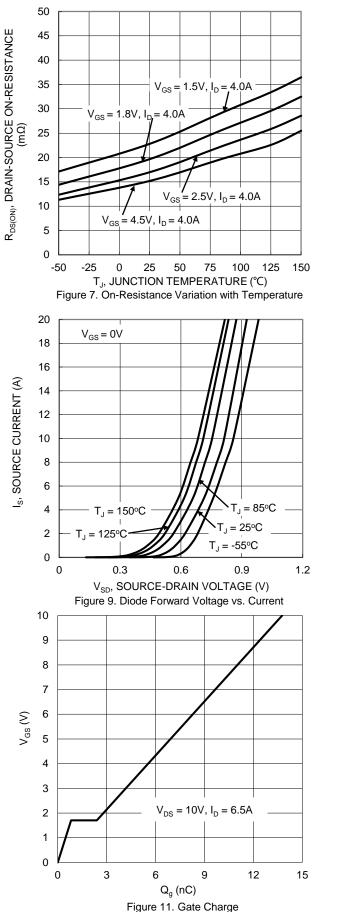
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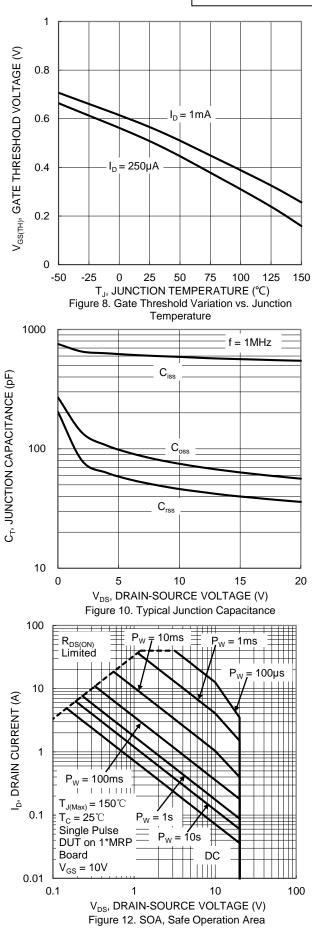


DMN2024UFDF Datasheet number: DS40595 Rev. 8 - 2 Downloaded from Arrow.com.



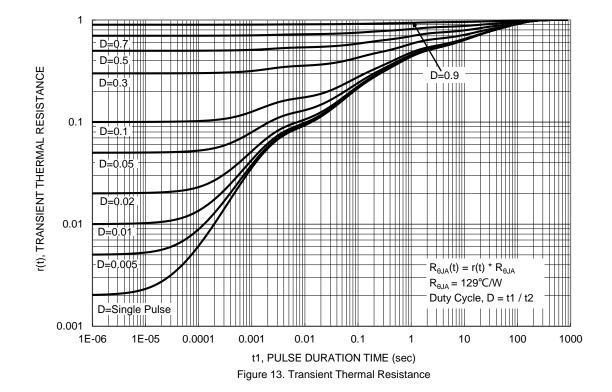






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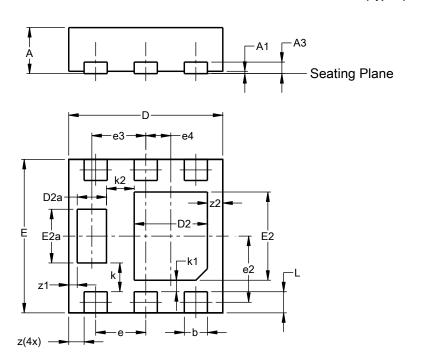






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



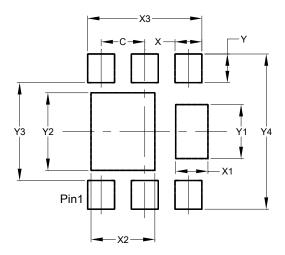
U-DFN2020-6								
		be F)						
Dim	Min	Max	Тур					
Α	0.57	0.60						
A1	0.00	0.05	0.03					
A3	-	-	0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
E	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
e		0.65 BS	С					
e2	().863 BS	SC					
e3		0.70 BS	С					
e4	().325 BS	SC					
k		0.37 BS	С					
k1		0.15 BS	С					
k2		0.36 BS	С					
L	0.225	0.325	0.275					
z		0.20 BS	С					
z1	().110 BS	SC					
z2		0.20 BS	С					
All C)imens	ions in	mm					

U-DFN2020-6 (Type F)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value
Dimensions	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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